NSN 5962-01-372-9756

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Bodv	l er	nath:
Douv	LCI	ıuıı.

Between 1.470 inches and 1.490 inches

Body Width:

Between 0.590 inches and 0.610 inches

Body Height:

Between 0.212 inches and 0.232 inches

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

Eo lorops

Features Provided:

Electrostatic sensitive and monolithic and programmed and tested to mil-std-883 and ultraviolet erasable and burn in, mil-std-883, class b

Inclosure Material:

Silicon

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Criticality Code Justification:

Feat

Case Outline Source And Designator:

D-10 mil-m-38510

Terminal Surface Treatment:

Solder

Product Name:

Microcircuit, programmed

Voltage Rating And Type Per Characteristic:

0.5 volts total supply and 7.0 volts total supply

Memory Device Type:

Eprom

Special Features:

Esd, power down, altered item using 67268, 5962-8953802xx

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

28 printed circuit

Specification Data:

67268-5962-89538 government standard

Shelf Life:

N/a

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Demilitarization:

Yes - demil/mli

Fiig:

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